



Journal of

**MATERIALS  
RESEARCH**

Volume 1, Number 6  
November/December 1986

Published for the Materials Research Society  
by the American Institute of Physics



# JOURNAL OF MATERIALS RESEARCH

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The *Journal of Materials Research* (ISSN: 0884-2914) is published six times a year by the American Institute of Physics for the Materials Research Society, 9800 McKnight Road, Suite 327, Pittsburgh, PA 15237. Membership in the MRS includes \$25.00 from membership dues to be applied to a subscription to the *Journal of Materials Research*. Second Class postage paid at Pittsburgh, PA and additional mailing offices. POSTMASTER: Send address changes to the *Journal of Materials Research* in care of the Materials Research Society, 9800 McKnight Road, Suite 327, Pittsburgh, PA 15237.

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CODEN: JMREEE

ISSN: 0884-2914

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The official documentation for *Journal of Materials Research* (i.e., inside front cover, instructions to authors, and indexing instructions) will be modified to reflect this change beginning with Number 1 of Volume 2, January/February 1987.

Since this is the final issue of *Journal of Materials Research* for which I am responsible, let me take the opportunity to express my gratitude and appreciation to Linda J. Kennedy, who served as editorial office supervisor from 1 July 1985 to 1 January 1987; to Judith Stonehill, who wrote and documented the custom software used on the editorial office personal computers; to Cliff Griffiths, who indexed all the papers published thus far in *Journal of Materials Research*; and to Mark Myers, Manager, of the Webster Research Center, who authorized Xerox to finance the start-up and ongoing operation of the Journal during 1985 and 1986. These individuals enabled the initiation of the editorial office operations in a timely fashion at no incremental cost to the Materials Research Society. It has been our pleasure and privilege to serve as the editorial office staff for *Journal of Materials Research*. We extend to the readers, authors, and principal editors of *Journal of Materials Research* our thanks for your support, and to Dr. Brown, Ms. Krysinski, and the MRS office staff our warmest best wishes for the future of the Journal.

Charles B. Duke  
Webster, New York  
December 1986

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